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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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## **Fast Recovery Epitaxial Diode (FRED)**

**DSEI 30** 

 $I_{FAVM} = 30 A$ 

 $V_{RRM} = 1000 V$ 

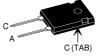
 $= 35 \, \text{ns}$ 

$\mathbf{V}_{RSM}$	$\mathbf{V}_{\mathtt{RRM}}$	Туре
<u>v</u>	V	
1000	1000	DSEI 30-10A
1000	1000	DSEI 30-10AR



**TO-247 AD** Version A





back surface

A = Anode, C = Cathode

\* Patent pending

Symbol Test Conditions		Maximum	Maximum Ratings		
FRMS (1)	$T_{VJ} = T_{VJM}$ $T_{C} = 85$ °C; rectangular, d = 0.5 $t_{p} < 10 \ \mu s$ ; rep. rating, pulse width limited by $T_{VJM}$	70 30 375	A A A		
1	T 45°C: + 10 mg (50 Hz) ging	200			

		t = 8.3  ms  (60  Hz),  sine	210	F
	$T_{VJ} = 150^{\circ}C;$	t = 10  ms  (50  Hz),  sine  t = 8.3  ms  (60  Hz),  sine	185 195	F F
I²t	T <sub>VJ</sub> = 45°C	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	200 180	A <sup>2</sup>

<sup>\*</sup> Verson A only; \*\* Version AR only

FRMS	$I_{VJ} = I_{VJM}$	70	Α
FAVM ①	$T_c = 85^{\circ}C$ ; rectangular, d = 0.5	30	Α
I <sub>FRM</sub>	$t_{p}$ < 10 $\mu s$ ; rep. rating, pulse width limited by $T_{v_{JM}}$	375	Α
I <sub>FSM</sub>	$T_{V,I} = 45$ °C; $t = 10$ ms (50 Hz), sine	200	Α
	t = 8.3  ms  (60  Hz),  sine	210	Α
	$T_{VI} = 150$ °C; $t = 10$ ms (50 Hz), sine	185	Α
	t = 8.3  ms  (60  Hz),  sine	195	Α
l²t	$T_{yy} = 45^{\circ}C$ $t = 10 \text{ ms } (50 \text{ Hz}), \text{ sine}$	200	A <sup>2</sup> s
	t = 8.3  ms  (60  Hz),  sine	180	$A^2s$
	$T_{VI} = 150^{\circ}\text{C}$ ; t = 10 ms (50 Hz), sine	170	A <sup>2</sup> s
	t = 8.3 ms (60 Hz), sine	160	$A^2s$
T <sub>vJ</sub>		-40+150	°C
T,,,,,		150	$^{\circ}\mathrm{C}$
T <sub>stg</sub>		-40+150	°C
P <sub>tot</sub>	T <sub>C</sub> = 25°C	138	W
M <sub>d</sub> *	Mounting torque	0.81.2	Nm
F <sub>c</sub>	mounting force with clip	20120	Ν
V <sub>ISOL</sub> **	50/60 Hz, RMS, t = 1 minute, leads-to-tab	2500	V~
Weight		6	g
	·		

Symbol	Test Conditions	Characteristic Value typ.   max.		
I <sub>R</sub>	$T_{VJ} = 25^{\circ}C$ $V_{R} = V_{RRM}$ $T_{VJ} = 25^{\circ}C$ $V_{R} = 0.8 \cdot V_{RRM}$ $T_{VJ} = 125^{\circ}C$ $V_{R} = 0.8 \cdot V_{RRM}$		750 250 7	μΑ μΑ mA
V <sub>F</sub>	$I_F = 36 \text{ A};$ $T_{VJ} = 150^{\circ}\text{C}$ $T_{VJ} = 25^{\circ}\text{C}$		2 2.4	V V
ν <sub>το</sub> r <sub>τ</sub>	For power-loss calculations only $T_{v,j} = T_{v,j,m}$		1.5 12.5	V mΩ
R <sub>thJC</sub> R <sub>thCK</sub> R <sub>thJA</sub>		0.25	0.9 35	K/W K/W K/W
t <sub>rr</sub>	$I_F = 1 \text{ A}; -di/dt = 100 \text{ A/}\mu\text{s}; V_R = 30 \text{ V}; T_{VJ} = 25^{\circ}\text{C}$	35	50	ns
I <sub>RM</sub>	$V_{R} = 540 \text{ V};  I_{F} = 30 \text{ A}; -di_{F}/dt = 240 \text{ A}/\mu\text{s}$ $L \leq 0.05 \mu\text{H}; T_{VJ} = 100^{\circ}\text{C}$	16	18	Α
@ I	'			

- · International standard package JEDEC TO-247 AD
- · Planar passivated chips
- · Very short recovery time
- · Extremely low switching losses
- Low I<sub>RM</sub>-values
- Soft recovery behavior
- Epoxy meets UL 94V-0
- Version AR isolated and UL registered E153432

## **Applications**

- · Antiparallel diode for high frequency switching devices
- Anti saturation diode
- · Snubber diode
- Free wheeling diode in converters and motor control circuits
- · Rectifiers in switch mode power supplies (SMPS)
- · Inductive heating and melting
- Uninterruptible power supplies (UPS)
- · Ultrasonic cleaners and welders

## **Advantages**

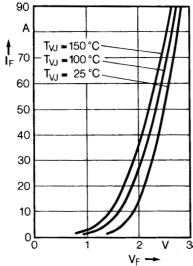
- · High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- · Low noise switching
- Low losses
- Operating at lower temperature or space saving by reduced cooling

IXYS reserves the right to change limits, test conditions and dimensions

**Features** 

①  $I_{FAVM}$  rating includes reverse blocking losses at  $T_{VJM}$ ,  $V_{R} = 0.8 V_{RRM}$ , duty cycle d = 0.5 Data according to IEC 60747





 $\, K_f \,$ 

1.0

0.8

0.6

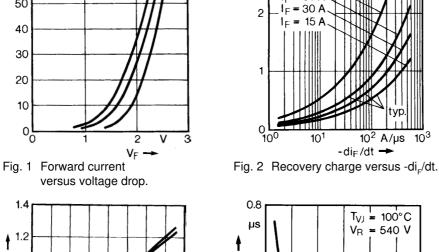
0.4

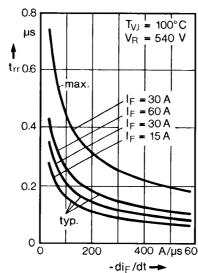
0.2

0

0

IRM





 $T_{VJ} = 100 \, ^{\circ}\text{C}$ 

μC

3

 $Q_{r_1}$ 

= 540

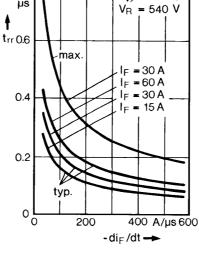
= 30 A

= 60 A

Fig. 4 Dynamic parameters versus junction temperature.

80

40



 $10^2 \text{ A/}\mu\text{s}$ 

Fig. 5 Recovery time versus -di<sub>F</sub>/dt.

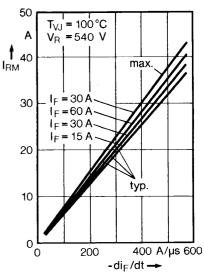


Fig. 3 Peak reverse current versus

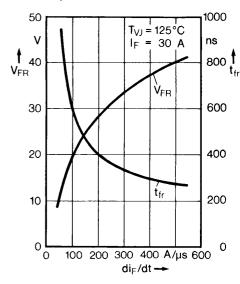


Fig. 6 Peak forward voltage versus di<sub>F</sub>/dt.

K/W ↑ 0.8 Z <sub>th</sub> JC						/	<b>-</b>						
0.6						_	$\parallel$				$\frac{1}{1}$		
0.4				/									
0.2							$\prod$						
0 1	0-3	10	) )-2		10	)-1		11	00	s t →		10	1

120°C 160

T<sub>VJ</sub> →

			-	t ·
Fig. 7	Transient th	ermal impedar	nce junction to case	

<u>†</u> E -	F B	
<u>G</u> _	A A A	M N

**Dimensions** 

Dim.	Millii	meter	Inc	hes
	Min.	Max.	Min.	Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G H	1.65	2.13 4.5	0.065	0.084 0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	2.2	2.54	0.087	0.102